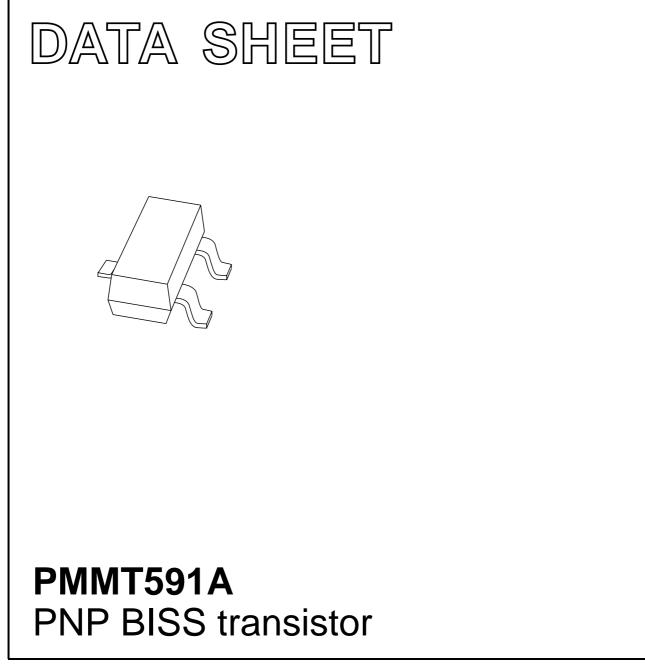
# DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2001 Jun 11 2004 Jan 13



#### Product data sheet

### **PNP BISS transistor**

#### FEATURES

- High current (max. 1 A)
- Low collector-emitter saturation voltage ensures reduced power consumption.

#### APPLICATIONS

• Battery powered units where high current and low power consumption are important.

#### DESCRIPTION

PNP BISS (Breakthrough In Small Signal) transistor in a SOT23 plastic package. NPN complement: PMMT491A.

#### MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>	
PMMT591A	9B*	

#### Note

- 1. \* = p : Made in Hong Kong.
- \* = t : Made in Malaysia.

\* = W : Made in China.

#### **ORDERING INFORMATION**

ТҮРЕ	PACKAGE		
NUMBER	NAME	DESCRIPTION	VERSION
PMMT591A	_	plastic surface mounted package; 3 leads	SOT23

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	collector-base voltage open emitter		-40	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current (DC)		-	-1	А
I <sub>CM</sub>	peak collector current		-	-2	А
I <sub>BM</sub>	peak base current		-	-1	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C; note 1$	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

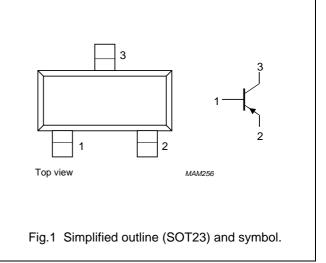
#### Note

1. Transistor mounted on an FR4 printed-circuit board.

### **PMMT591A**

#### PINNING

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



## PMMT591A

Product data sheet

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	note 1	500	K/W	

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### CHARACTERISTICS

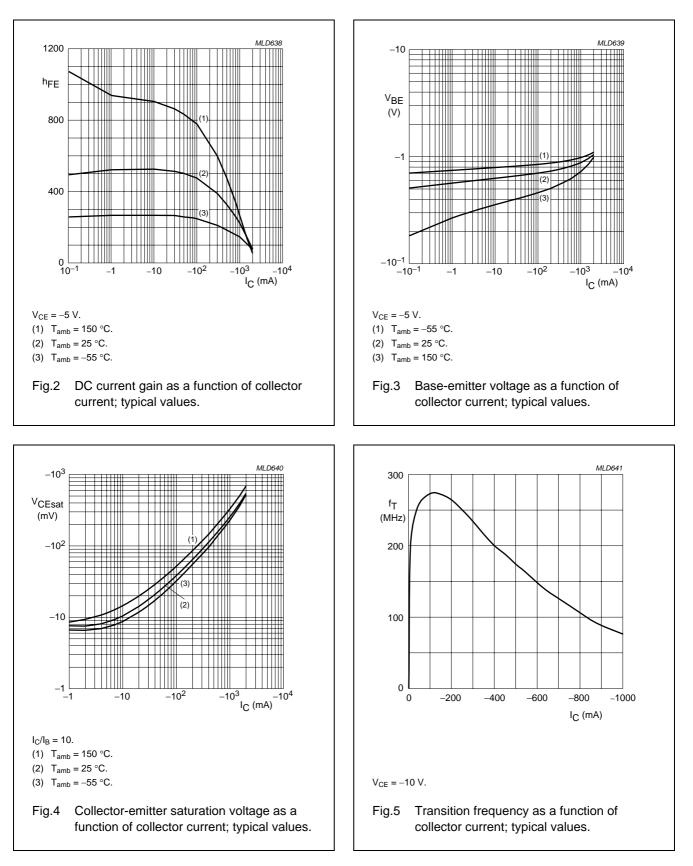
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = -30 V	-	-100	nA
I <sub>CEO</sub>	collector cut-off current	I <sub>B</sub> = 0; V <sub>CE</sub> = -30 V	-	-100	nA
I <sub>EBO</sub>	emitter cut-off current	$I_{C} = 0; V_{EB} = -5 V$	_	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 V$ ; note 1			
		$I_{\rm C} = -1  \rm{mA}$	300	_	
		I <sub>C</sub> = -100 mA	300	800	
		I <sub>C</sub> = -500 mA	250	_	
		$I_{\rm C} = -1$ A	160	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	note 1			
		$I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -1 \text{ mA}$	_	-200	mV
		$I_{\rm C} = -500 \text{ mA}; I_{\rm B} = -20 \text{ mA}$	_	-350	mV
		$I_{\rm C} = -1$ A; $I_{\rm B} = -100$ mA	-	-500	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C} = -1 \text{ A}; I_{B} = -50 \text{ mA}; \text{ note } 1$	_	-1.1	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ A}; \text{ note } 1$	-	-1	V
C <sub>c</sub>	collector capacitance	$I_E = I_e = 0; V_{CB} = -10 V; f = 1 MHz$	-	12	pF
f <sub>T</sub>	transition frequency	$I_{C} = -50 \text{ mA}; V_{CE} = -10 \text{ V}; \text{ f} = 100 \text{ MHz}$	150	-	MHz

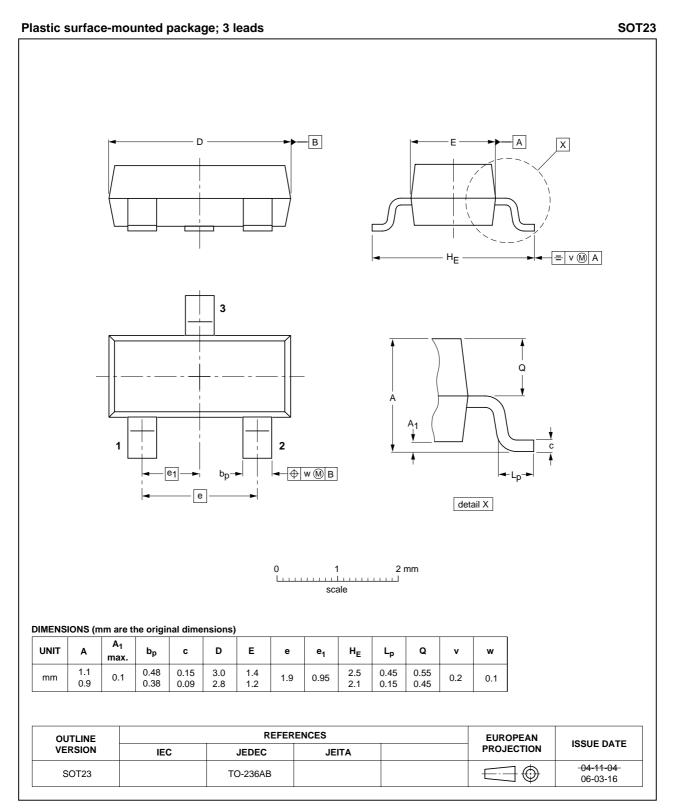
#### Note

1. Pulse test:  $t_p \leq 300~\mu s;~\delta \leq 0.02.$ 

### PMMT591A



#### PACKAGE OUTLINE



### PMMT591A

PMMT591A

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

- 1. Please consult the most recently issued document before initiating or completing a design.
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# **NXP Semiconductors**

#### **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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